LOW POWER LOW OFFSET VOLTAGE DUAL COMPARATORS

General Description

The MB393 consists of two independent precision voltage comparators with an offset voltage specification as low as 2.0 mV max for two comparators which were designed specifically to operate from a single power supply over a wide range of voltages. Operation from split power supplies is also possible and the low power supply current drain is independent of the magnitude of the power supply voltage. These comparators also have a unique characteristic in that the input common-mode voltage range includes ground, even though operated from a single power supply voltage.

Application areas include limit comparators, simple analog to digital converters; pulse, square wave and time delay generators; wide range VCO; MOS clock timers; multi vibrators and high voltage digital logic gates. The MB393 was designed to directly interface with TTL and CMOS. When operated from both plus and minus power supplies, the LM393 will directly interface with MOS logic where their low power drain is a distinct advantage over standard comparators.

The MB393 is available in standard DIP-8 and SOP-8 packages.

Features

- Wide Power Supply Voltage: Single Supply: 3V to 36V Dual Supplies: ±1.5V to ±18V
- Very low supply current drain (0.5 mA) independent of supply voltage
- Low input biasing current: 25 nA
- Low input offset current:: ±5 nA
- Maximum offset voltage: 5 mV
- Input common-mode voltage range includes ground
- Differential input voltage range equal to the power supply voltage
- Low output saturation voltage: 200 mV at 4 mA Output voltage compatible with TTL, DTL, ECL, MOS and CMOS logic systems



CBC Microelectronics http://www.cbcv.net

Applications

- Battery Charger
- Cordless Telephone
- Switching Power Supply
- DC-DC Module, PC Motherboard



Figure 1: Package Types of MB393

Pin Configuration (DIP8 / SOP8)



Figure 2: Pin Configuration of MB393 (Top View)

CBC Microelectronics Co., LTD October, 2006-rev 1.0

Ordering Information



	Part	Number	Ма		
Package	Pb-free	Halogen-Free	Pb-free	Halogen-Free	Packing Type
SOP-8	MB393M	MB393GM	MB393M	MB393GM	Tube
	MB393MTR	MB393GMTR	MB393M	MB393GM	Tape & Reel
DIP-8	MB393P	MB393GP	MB393P	MB393GP	Tube

Typical Application







Figure 5: One Shot Multivibrator



Figure 4: Driving CMOS



Figure 6: Squarewave Oscillator

CBC Microelectronics Co., LTD October, 2006-rev 1.0

Functional Block Diagram



Figure 7: Functional Block Diagram of MB393 (Each Amplifier)

Absolute Maximum Ratings (Note 1)

Parameter	Symbol	Value	Unit
Power Supply Voltage	Vcc	40	V
Differential Input Voltage	Vid	40	V
Input Voltage	Vic	-0.3 to 40	V
Input Current (VIN < -0.3V)	lin	50	mA
Power Dissipation	Do	DIP-8: 780	mW
	SOP-8: 550		mW
Storage Temperature Range	Tstg	-55 to 150	
Lead Temperature (Soldering, 10 Seconds)		260	

Note1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

CBC Microelectronics Co., LTD October, 2006-rev 1.0

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit	
Supply Voltage	Vcc	3	36	V	
Ambient Operating Temperature	ТА	-20	+85		

Electrical Characteristics

Vcc = 5V, GND = 0V, TA = 25 unless otherwise specified.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Input Offset Voltage	Vio	Vo=1.4V,Rs=0 Vcc=5V to 30V		2	5	mV
Input Bias Current	IBIAS	IIN+ or IIN-, VCM=0V		25	250	nA
Input Offset Current	lio	IIN+ - IIN-, VCM=0V		5	50	nA
Input Common Mode Voltage Range	Vir	Vcc=30V	0		Vcc- 1.5	V
Cumply Current	Icc	Vcc=30V		0.7	1.7	mA
		Vcc=5V		0.5	1.0	mA
Large Signal Voltage Gain	Gv	Vcc=15V,Vo=1V to 11V RL≥15KΩ	50	200		V/mV
Large Signal Response Time	t	VIN = TTL Logic Swing, VREF = 1.4V, VRL = 5V, RL = 5.1k		200		ns
Response Time		VRL = 5V, RL = 5.1K		1.3		us
Output Sink Current	Isink	V+=0V, V-=1V, Vo=1.5V	6	16		mA
Saturation Voltage	VSAT	V+=0V, V-=1V, ISINK ≤ 4mA		200	400	mV
Output Leakage Current	ILEAK	V+=1V, V-=0V, Vo=1.5V		0.1		nA

100

Typical Performance Characteristics



- - T_A=-40°C -----T_=0°C 80 . T_=25℃ •••T_=70°C Input Bias Current (nA) 20 0 15 25 30 35 40 Б 20 10 Supply Voltage (V)

Figure 8: Supply Voltage vs. Supply Current

Figure 9: Supply Voltage vs. Input Bias Current

CBC Microelectronics Co., LTD October, 2006-rev 1.0



Typical Performance Characteristics (Continued)

Figure 10: Output Sink Current vs. Saturation Voltage

Figure 11: Response Time for 5mV Input Overdrive-Negative Transition





Overdrive-Positive Transition

CBC Microelectronics Co., LTD October, 2006-rev 1.0

Mechanical Dimensions



CBC Microelectronics Co., LTD October, 2006-rev 1.0

Mechanical Dimensions (Continued)



CBC Microelectronics Co., LTD October, 2006-rev 1.0

IMPORTANT NOTICE

CBC Microelectronics Co., LTD reserves the right to make changes without further notice to any products or specifications herein. CBC Microelectronics Co., LTD does not assume any responsibility for use of any its products for any particular purpose, nor does CBC Microelectronics Co., LTD assume any liability arising out of the application or use of any its products or circuits. CBC Microelectronics Co., LTD does not convey any license under its patent rights or other rights nor the rights of others.

CBC Microelectronics Co., LTD October, 2006-rev 1.0